

CDBV3-54/S/C/A-G

Reverse Voltage: 30 Volts
Forward Current: 200 mA
RoHS Device



Features

- Design for mounting on small surface.
- High speed switching application, circuit protection.
- Low turn-on voltage.

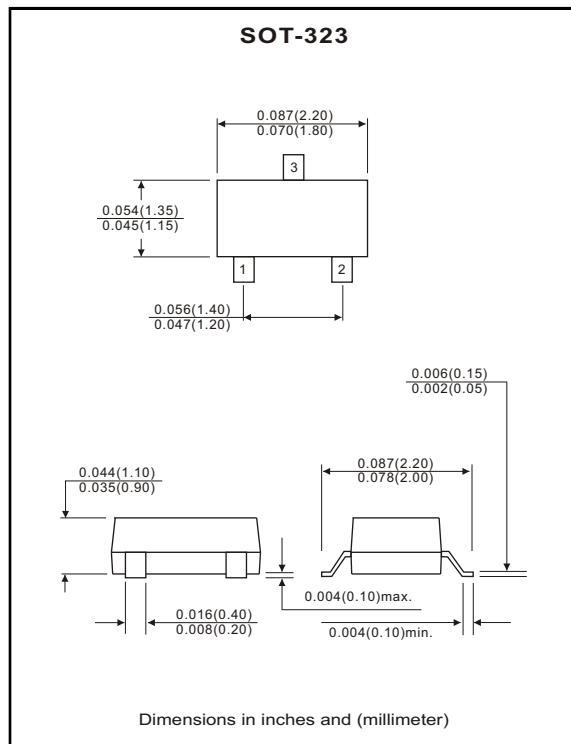
Mechanical data

- Case: SOT-323, molded plastic.
- Terminals: solderable per MIL-STD-750, method 2026.
- Approx. weight: 0.006 grams

Circuit diagram



CDBV3-54-G CDBV3-54S-G CDBV3-54C-G CDBV3-54A-G



Maximum Ratings and Electrical Characteristics

(at $T_a=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Conditions	Value	Units
Repetitive peak reverse voltage	V_{RRM}		30	V
Reverse voltage	V_R		30	V
Forward current	I_F		200	mA
Peak surge forward current	I_{FSM}	$T=1.0 \text{ sec}$	0.6	A
Power dissipation	P_D		200	mW
Maximum forward voltage	V_F	@ $I_F=0.1\text{mA}$ @ $I_F=1\text{mA}$ @ $I_F=10\text{mA}$ @ $I_F=30\text{mA}$ @ $I_F=100\text{mA}$	0.24 0.32 0.40 0.50 1.00	V
Maximum reverse current	I_R	@ $V_R=25\text{V}$	2	μA
Maximum reverse recovery time	T_{rr}	$I_F=I_R=10\text{mA}$, $R_L=100\Omega$	4	nS
Maximum diode capacitance	C_J	$V_R=1\text{V}$, $f=1.0\text{MHz}$	10	pF
Maximum junction temperature	T_J		125	$^\circ\text{C}$
Storage temperature	T_{STG}		-65 to +125	$^\circ\text{C}$

Small Signal Schottky Diodes

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RATING AND CHARACTERISTIC CURVES (CDBV3-54/S/C/A-G)

Fig.1 Forward Characteristics

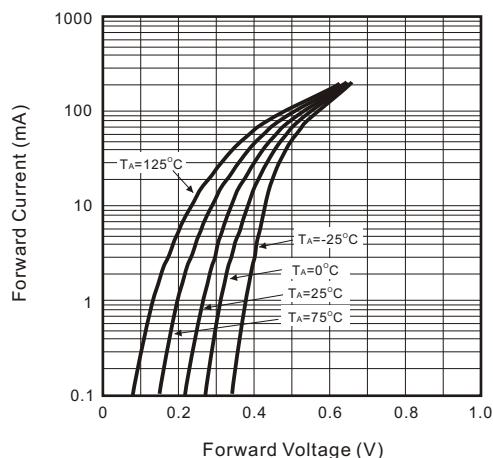


Fig.2 Reverse Characteristics

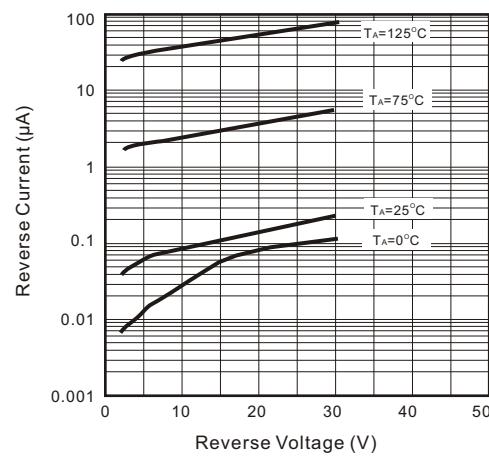


Fig.3 Capacitance Between Terminals Characteristics

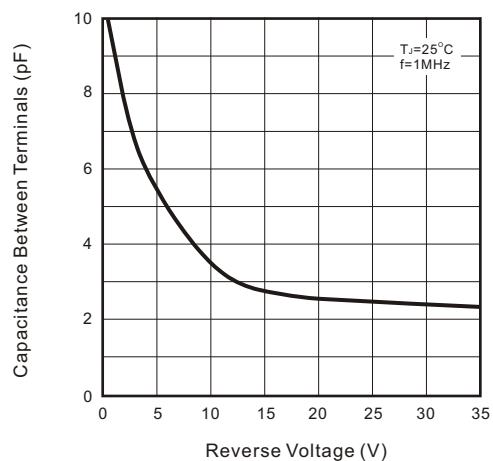


Fig.4 Current Derating Curve

